
Assignment 3

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Part1

In this part of the assignment the code from assignment 1 that uses the Monte Carlo method to simulate random motion of electrons was modified to include the effects of having an electric field exist within the material. In this case the simulation models a scenario where 0.1 V is applied across the $x=0$ and $x=L$ terminals of the device. Because the region we are simulating is rectangular, we can assume that the electric field is constant and exists only in the x -direction. Therefore, the first step in the simulation is to calculate the force on each electron, as shown below.

```
%simulation constants
L = 200e-9; %Length of region (x axis)
W = 100e-9; %Width of region (y axis)
K = 1.3806e-23;
m = 0.26*9.1093e-31;
q = 1.60217662e-19;
```

```
%Calculate force on electrons
V = 0.1;
Fx = -q*V/L;
```

The magnitude of this force -8.0109×10^{-14} N in the x direction. The next step in the code is to assign the position and velocities for each electron, as well as some other setup for the simulation, very much like what was done in assignment 1. This code is shown below.

```
%Place electrons in Boundary
x = L*rand(1000,1);
y = W*rand(1000,1);

% Calculate how many electrons each "particle" in the simulation
represents
electronConcentration = 10^15*1e4;

electronsPerParticle = electronConcentration*W*L/1000;

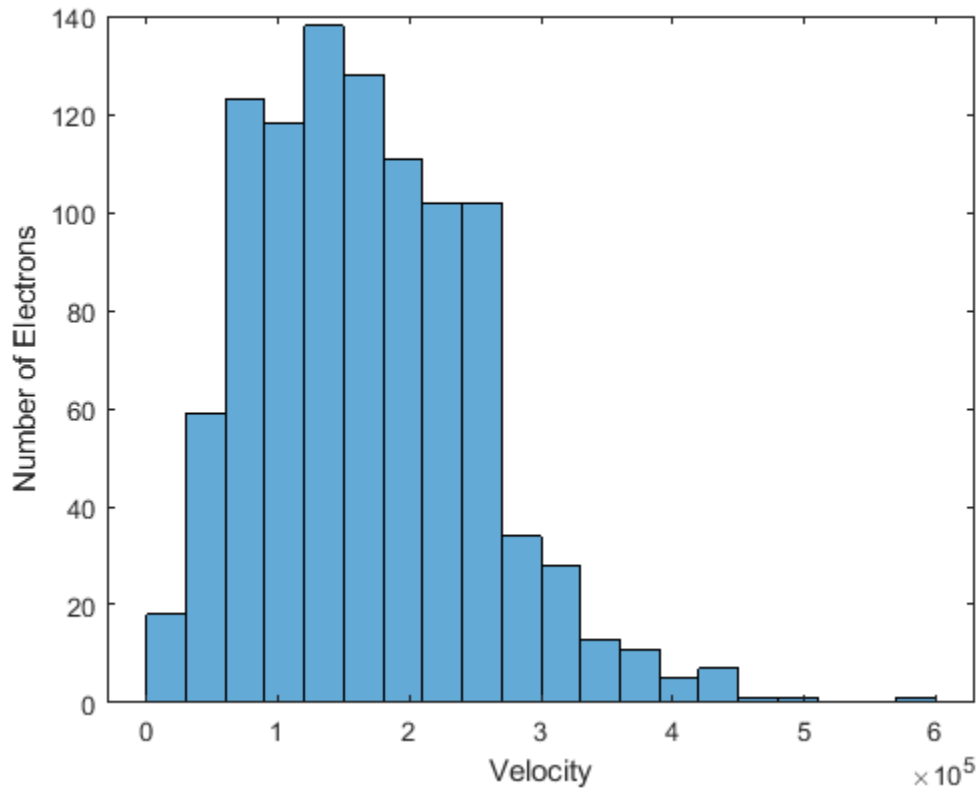
% Assign electron velocity based on Maxwell Boltzman Distribution
T = 300;
std = sqrt(K*T/m);
vth = sqrt(2*K*T/m);
Vx = normrnd(0,std,[1000,1]);
Vy = normrnd(0,std,[1000,1]);
V = sqrt(Vx.^2 + Vy.^2); %Now it is important to check that the
    velocities were assigned correctly by confirming that the average
```

```

    velocity is close to the thermal velocity and by plotting a histogram
    of the velocity.
dt = 100e-9/vth/100;
figure(2)
histogram(V);
xlabel('Velocity')
ylabel('Number of Electrons')

%Initialize variables to plot
Tplot = zeros(300);
Ix = zeros(300);

```



Now the the electrons are setup, their trajectories can be calculated. The code that handles electron scattering and reflection off the simulation boundaries is exactly the same as in assignment 1. Since there is now a force acting on each electron, the code that updates the electron position had to be changed. The position and velocity in the x direction are now updated using the following kinematic equations. $x_2 = x_1 + V_{x1} \cdot dt + 0.5 \cdot F_x \cdot dt^2 / m$ and $V_{x2} = V_{x1} + F_x \cdot dt / m$. Additionally, the current density is calculated by the product of the mean velocity, the electron density, and the electric charge, and the current is found by multiplying the current density times the area of the region. zthe current is plotted as a function of timestep. The code for this section is shown below.

```

for i =1:300
    xold = x;
    yold = y;

    % Define region boundaries and rules for interacting with
    boundaries

```

```

xboundRight = x > L;
xboundLeft = x < 0;
ybound = (y > W) | (y < 0);
x(xboundRight) = x(xboundRight) - L;
x(xboundLeft) = x(xboundLeft) + L;
xold(xboundRight | xboundLeft) = x(xboundRight | xboundLeft);
Vy(ybound) = -Vy(ybound);

%Update Position
x = x + Vx*dt + 0.5*Fx*dt^2/m;
y = y + Vy*dt;
Vx = Vx + Fx*dt/m;

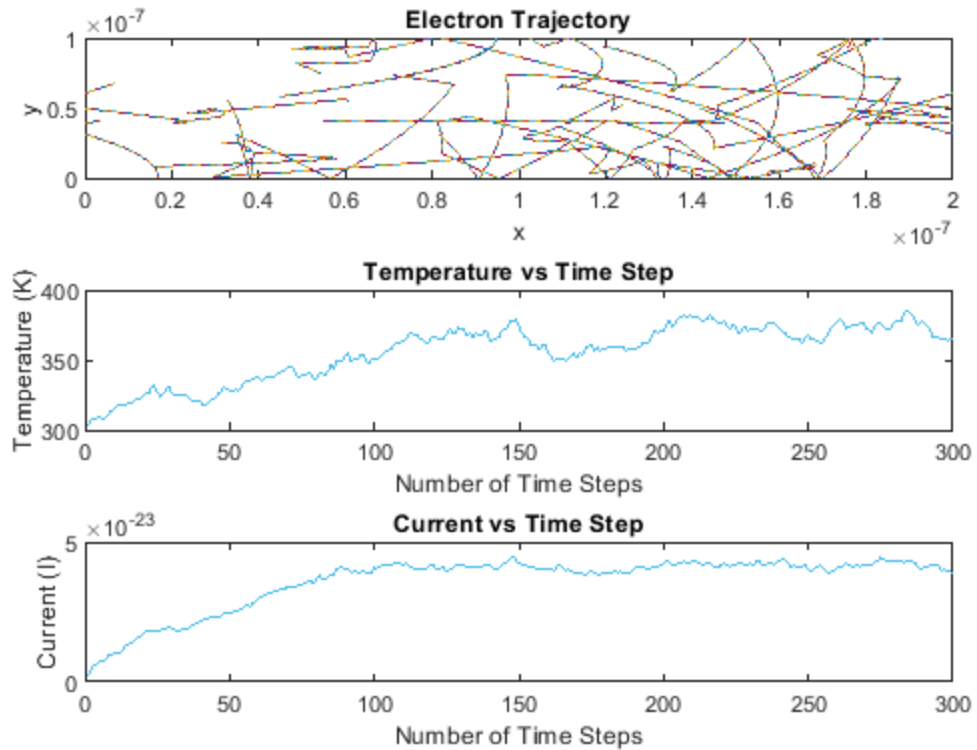
% Determine Witch electrons scatter and update velocity
scatter = rand(1000,1) < (1 - exp(-dt/0.2e-12));
Vx(scatter) = normrnd(0,std,size(Vx(scatter)));
Vy(scatter) = normrnd(0,std,size(Vy(scatter)));

xplot = transpose([xold(1:10) x(1:10)]);
yplot = transpose([yold(1:10) y(1:10)]);
Tplot(i) = (1/(2*K))*mean(Vx.^2 + Vy.^2)*m;

%Current density and Current Calculations
Jx = mean(Vx)*1000*electronsPerParticle*(-q);
Ix(i) = Jx*W*L;
figure(2)
subplot(3,1,1);
plot(xplot,yplot)
xlim([0 L])
ylim([0 W])
title('Electron Trajectory')
xlabel('x')
ylabel('y')
hold on
subplot(3,1,2)
plot(Tplot(1:i))
title('Temperature vs Time Step')
xlabel('Number of Time Steps')
ylabel('Temperature (K)')
hold on
subplot(3,1,3)
plot(Ix(1:i))
title('Current vs Time Step')
xlabel('Number of Time Steps')
ylabel('Current (I)')
hold on
drawnow

end

```



As shown in the current vs time plot, when the simulation is initially started, the electrons are moving in random directions with a mean drift velocity of zero. This results in an overall current of 0. The electrons are then accelerated in the negative-x direction by the electric field, and the current begins to increase. After a while the current levels off and stays relatively constant because the scattering of the electrons with the lattice combined with the effects of the electric field produce a constant drift velocity. The next step is to plot the electron density and temperature distributions. This is shown below.

```
% Show electron distribution
figure(3);
hist3([x y], 'CdataMode', 'auto');
view(2);
title('Electron Density');
colorbar;
xlabel('x (m)');
ylabel('y (m)');
title('Electron Density Heat Map');

temp_sum_x = zeros(20,10);
temp_sum_y = zeros(20,10);
temp_num = zeros(20,10);

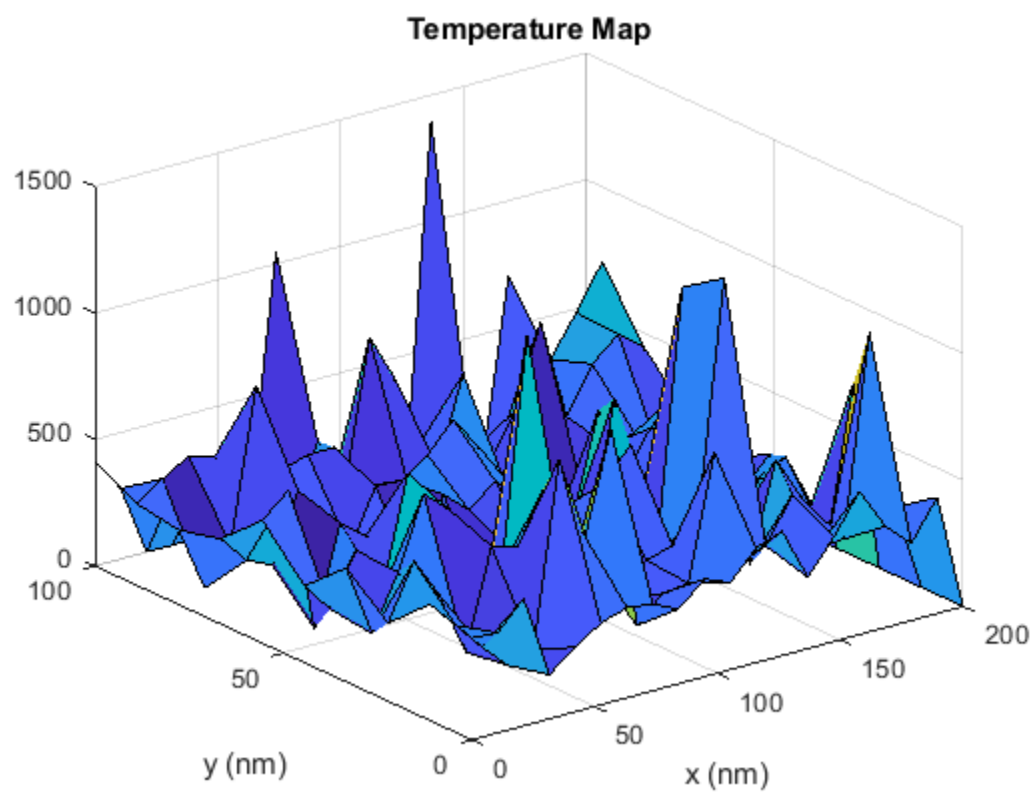
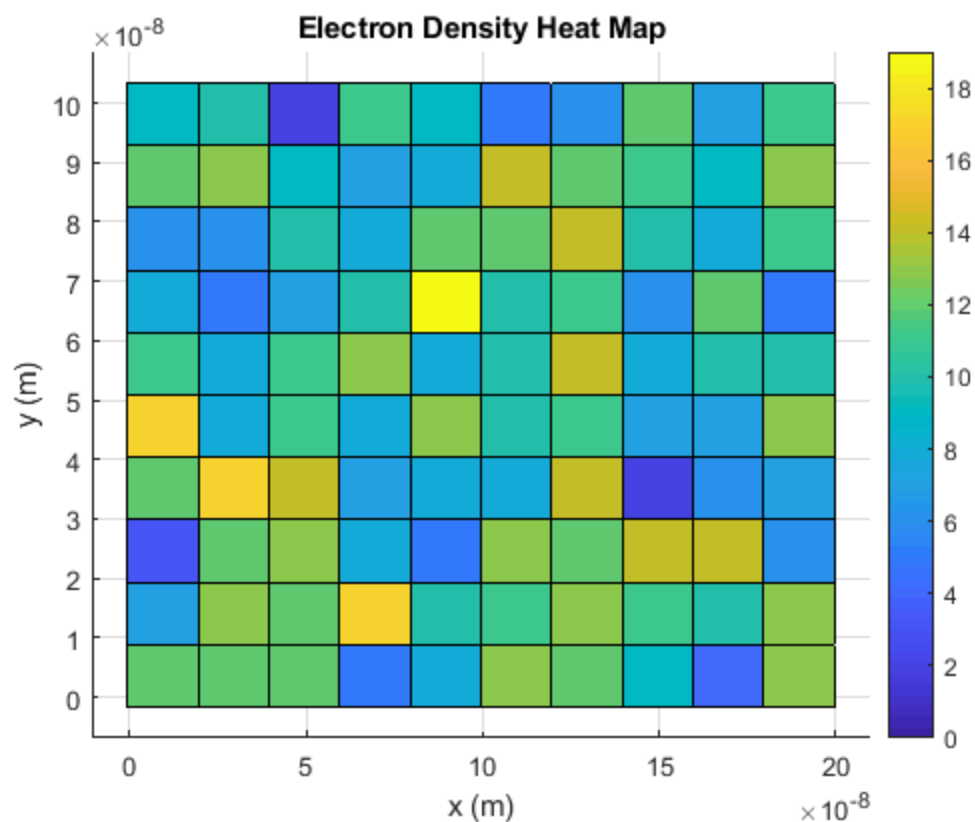
for i=1:1000
    % Find which "bin" it belongs in:
    x1 = floor(x(i)/1e-8);
    y1 = floor(y(i)/1e-8);
    if(x1<=0)
```

```
x1 = 1;
end
if(y1<=0)
y1= 1;
end
if(y1>10)
    y1 = 10;
end
if(x1>20)
    x1=20;
end
% Add its velocity components to the cumulative count:
temp_sum_y(x1,y1) = temp_sum_y(x1,y1) + Vy(i).^2;
temp_sum_x(x1,y1) = temp_sum_x(x1,y1) + Vx(i).^2;
temp_num(x1,y1) = temp_num(x1,y1) + 1;

end

temp = (temp_sum_x + temp_sum_y).*m./K./2./temp_num;
temp(isnan(temp)) = 0;
temp = transpose(temp);

figure(4)
%Plot temperature distribution
[X Y] = meshgrid(linspace(0,200,20),linspace(0,100,10));
surf(X,Y,temp)
title('Temperature Map');
xlabel('x (nm)');
ylabel('y (nm)');
zlim([0 1500]);
```



Part 2

In this part of code I use the finite difference approximation to determine the electric field inside the bottleneck region of assignment 2. This code is essentially identical to the code from the second assignment so I won't go over the code and the results in detail but I will show them below.

```
clear all

L = 200e-9;
W = 100e-9;
Lb = 40e-9;
Wb = 40e-9;
meshspace = 1e-9;
V = 0.8;
nx = round(L/meshspace + 1);
ny = round(W/meshspace + 1);

cond1 = 1;
cond2 = 1e-2;

%This section creates a conductivity map which assigns a conductivity
%to
%each node in the mesh. This will be used to create the G matrix
condMap = zeros(nx,ny);

for i = 1:nx
    for j = 1:ny
        if (i-1)>0.5*(L-Lb)/meshspace && (i-1)<0.5*(L+Lb)/
meshspace && ((j-1)<Wb/meshspace || (j-1)>(W-Wb)/meshspace)
            condMap(i,j) = cond2;
        else
            condMap(i,j) = cond1;
        end
    end
end

figure(5)
imagesc([0 W],[0 L],condMap);
colorbar
xlabel('y')
ylabel('x')
title('conductivity vs position')

G = sparse(nx*ny);
B = zeros(1,nx*ny);
for i = 1:nx
    for j = 1:ny
        n = j + (i-1)*ny;

        %V=1 @ x=0 BC
        if i == 1
            G(n,n) = 1;
        end
    end
end
```

```

B(n) = V;

%V=0 @ x=L BC
elseif i == nx
    G(n,n) = 1;

%Absorbing BC @ y=0
elseif j == 1
    nxm = j + (i-2)*ny;
    nxp = j + i*ny;
    nyp = j+1 + (i-1)*ny;

    %Resistor Values from conduction map
    rxm = (condMap(i,j) + condMap(i-1,j))/2;
    rxp = (condMap(i,j) + condMap(i+1,j))/2;
    ryp = (condMap(i,j) + condMap(i,j+1))/2;

    %node equations from resistor values
    G(n,n) = -(rxm + rxp + ryp);
    G(n,nxm) = rxm;
    G(n,nxp) = rxp;
    G(n,nyp) = ryp;

%Absorbing BC @ y=W
elseif j == ny
    nxm = j + (i-2)*ny;
    nxp = j + i*ny;
    nym = j-1 + (i-1)*ny;

    %Resistor Values from conduction map
    rxm = (condMap(i,j) + condMap(i-1,j))/2;
    rxp = (condMap(i,j) + condMap(i+1,j))/2;
    rym = (condMap(i,j) + condMap(i,j-1))/2;

    %node equations from resistor values
    G(n,n) = -(rxm + rxp + rym);
    G(n,nxm) = rxm;
    G(n,nxp) = rxp;
    G(n,nym) = rym;

%internal nodes
else
    nxm = j + (i-2)*ny;
    nxp = j + i*ny;
    nym = j-1 + (i-1)*ny;
    nyp = j+1 + (i-1)*ny;

    %Resistor Values from conduction map
    rxm = (condMap(i,j) + condMap(i-1,j))/2;
    rxp = (condMap(i,j) + condMap(i+1,j))/2;
    ryp = (condMap(i,j) + condMap(i,j+1))/2;
    rym = (condMap(i,j) + condMap(i,j-1))/2;

    %node equations from resistor values

```



```

        G(n,n) = -(rxm + rxp + rym + ryp);
        G(n,nxm) = rxm;
        G(n,nxp) = rxp;
        G(n,nym) = rym;
        G(n,nyp) = ryp;

    end
end
end

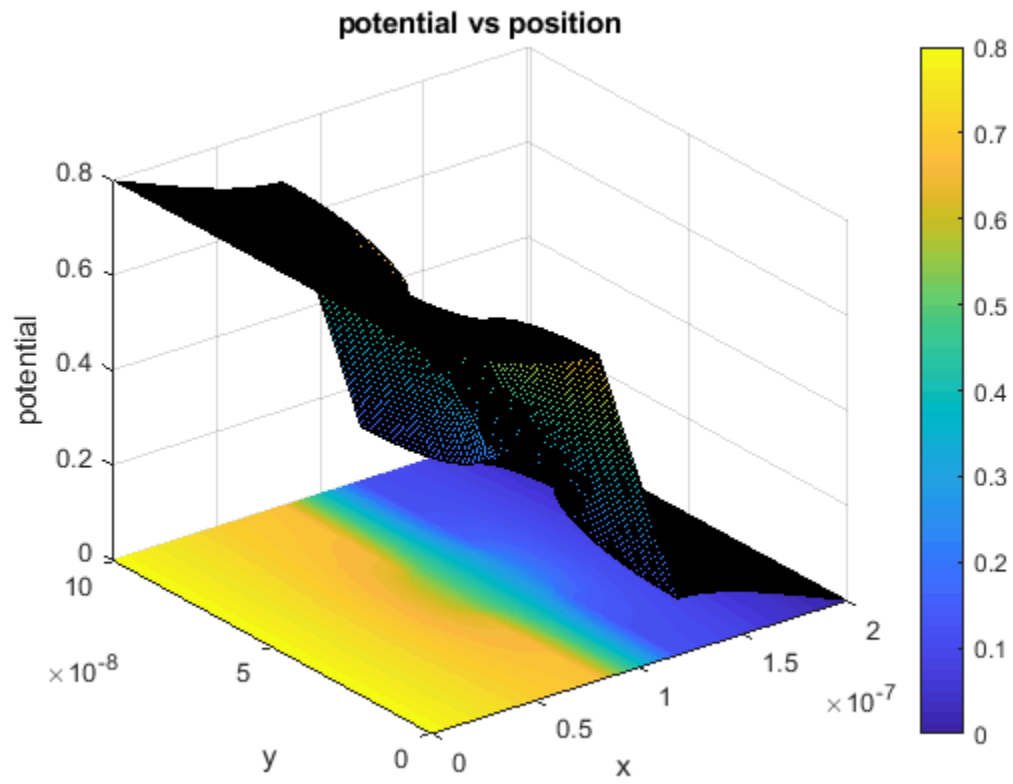
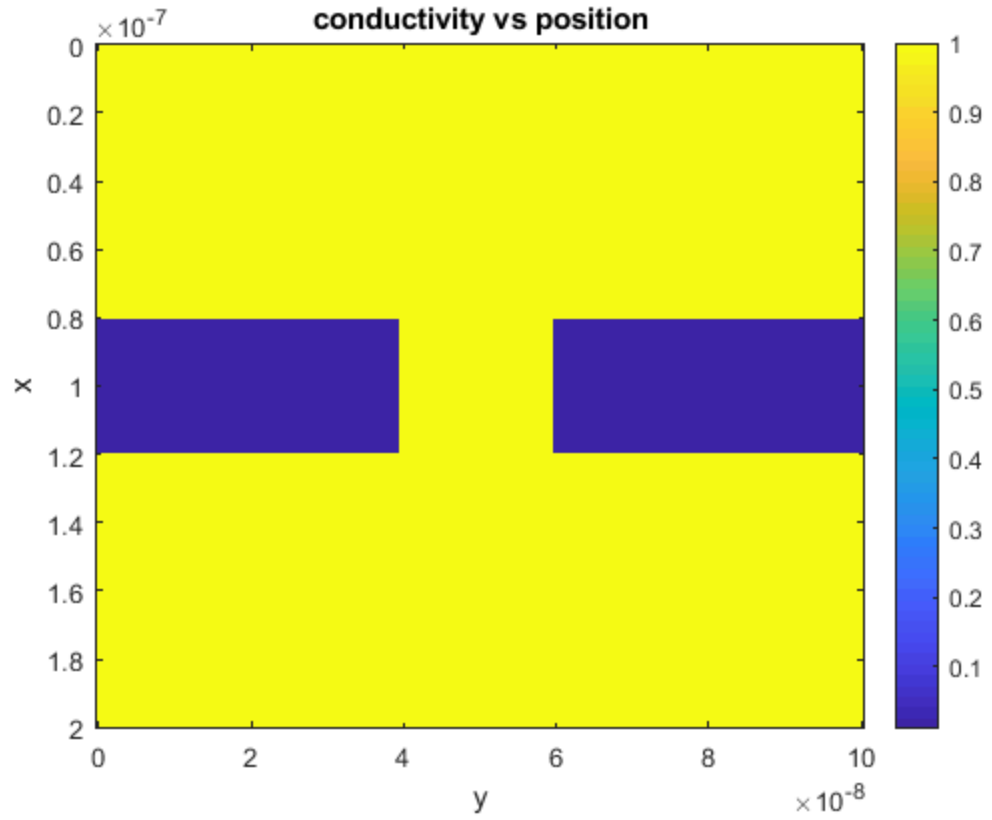
%solving and plotting
V = G\B';
Vmap = zeros(nx,ny);
for i = 1:nx
    for j = 1:ny
        n = j + (i-1)*ny;
        Vmap(i,j) = V(n);
    end
end

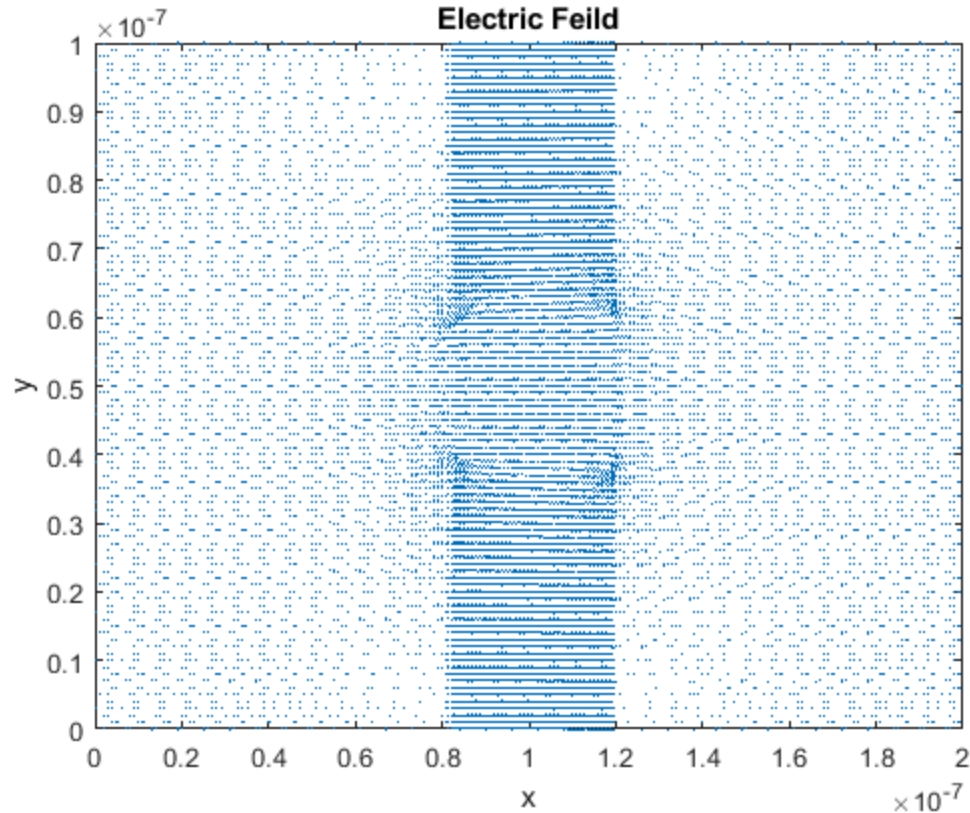
[X, Y] = meshgrid(0:meshspace:L,0:meshspace:W);
figure(6)
surf(X',Y',Vmap)
colorbar
hold on
imagesc([0 L],[0 W],Vmap')
xlabel('x')
ylabel('y')
zlabel('potential')
title('potential vs position')
hold off

[Ey, Ex] = gradient(Vmap,meshspace);
Ex = -Ex;
Ey = -Ey;

figure(7)
quiver(X',Y',Ex,Ey)
xlim([0 L])
ylim([0 W])
xlabel('x')
ylabel('y')
title('Electric Feild')

```





Part 3

in this part of the assignment parts 1 and 2 are mixed together. The electric feild calculated in part 2 is used in a Monte Carlo Simulation to determine the trajectories of the electrons through the bottleneck. The following code is used to set up the basic parameters for the simulation.

```
%Constants
K = 1.3806e-23;
m = 0.26*9.1093e-31;
q = 1.60217662e-19;

%Place electrons in Boundary
x = L*rand(1000,1);
y = W*rand(1000,1);

yboundSpecular = true; %Specular reflection when treu, diffuse
                           otherwise;
xboundSpecular = true;
boxSpecular = true;

%Determines if any electrons are in the box and moves them out
inbox1 = x > 0.5*(L-Lb) & x < 0.5*(L+Lb) & y > (W-Wb);
inbox2 = x > 0.5*(L-Lb) & x < 0.5*(L+Lb) & y < Wb;
x(inbox1) = x(inbox1) + ((rand() > 0.5)*2 -
1)*Lb*rand(size(x(inbox1)));
```

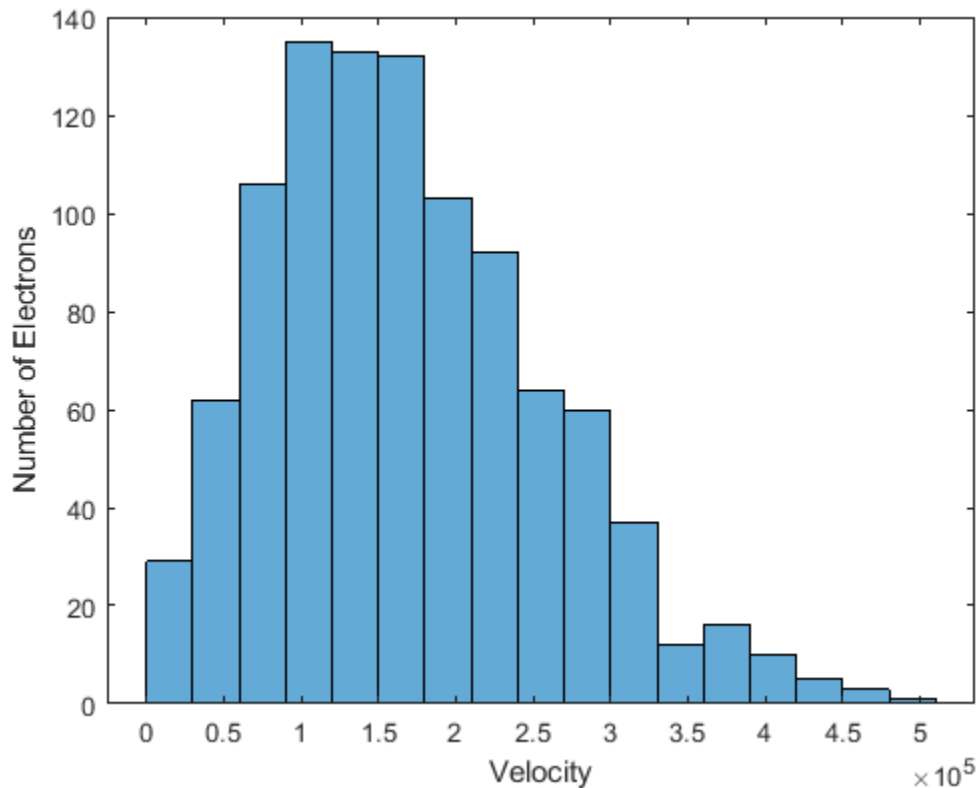
```

x(inbox2) = x(inbox2) + ((rand() > 0.5)*2 -
    1)*Lb*rand(size(x(inbox2)));
y(inbox1) = y(inbox1) - 0.5*Wb*rand(size(y(inbox1)));
y(inbox2) = y(inbox2) + 0.5*Wb*rand(size(y(inbox2)));

% Assign electron velocity based on Maxwell Boltzman Distribution
T = 300;
vth = sqrt(2*K*T/m);
std = sqrt(K*T/m);
Vx = normrnd(0,std,[1000,1]);
Vy = normrnd(0,std,[1000,1]);
V = sqrt(Vx.^2 + Vy.^2);
figure(8)
histogram(V);
xlabel('Velocity')
ylabel('Number of Electrons')
Tplot = zeros(1000,1); %calculated temperature for plotting

dt = 100e-9/vth/100;

```



The next step is to determine the force acting on each electron. In this simulation the electric field is only defined on discrete intervals of 1 nm. Therefore, we need to determine the electric field at the closest mesh point for each electron then determine the force acting on the electrons. This is shown below.

```
Fx = zeros(1000,1);
```

```

Fy = zeros(1000,1);
for i = 1:1000
    Fx(i) = -q*Ex(round(1e9*(x(i)+1e-9)),round(1e9*(y(i)+1e-9)));
    Fy(i) = -q*Ey(round(1e9*(x(i)+1e-9)),round(1e9*(y(i)+1e-9)));
end

% The electron trajectories are calculated using the code shown below.

Tplot = zeros(1000);
xold = x;
yold = y;
for i =1:1000
    %Defines the boundaries of the simulation as well as the boxes
    yboundTop = y > W;
    yboundBottom = y < 0;
    inbox1 = x >= 80e-9 & x <= 120e-9 & y >= 60e-9;
    inbox2 = x >= 80e-9 & x <= 120e-9 & y <= 40e-9;
    xboundRight = x > L;
    xboundLeft = x < 0;

    %Reflection off of xboundary
    if xboundSpecular
        Vx(xboundRight | xboundLeft) = - Vx(xboundRight | xboundLeft);
    else
        theta = pi*rand();
        Vx(xboundRight | xboundLeft) = V(xboundRight |
xboundLeft)*cos(theta);
        Vy(xboundRight | xboundLeft) = V(xboundRight |
xboundLeft)*sin(theta);
    end

    %Reflection off of y boundary
    if yboundSpecular
        Vy(yboundTop | yboundBottom) = -Vy(yboundTop | yboundBottom);
    else
        theta = pi*rand();
        Vy(yboundTop | yboundBottom) = V(yboundTop |
yboundBottom)*cos(theta);
        Vx(yboundTop | yboundBottom) = V(yboundTop |
yboundBottom)*sin(theta);
    end

    %Reflection off of box
    if boxSpecular
        %Reflection off of verticle face
        Vx(inbox1 & yold >= 60e-9) = -Vx(inbox1 & yold >= 60e-9);
        Vx(inbox2 & yold <= 40e-9) = -Vx(inbox2 & yold <= 40e-9);

        %Reflection off of Horizontal face
        Vy(inbox1 & yold <= 60e-9) = -Vy(inbox1 & yold <= 60e-9);
        Vy(inbox2 & yold >= 40e-9) = -Vy(inbox2 & yold >= 40e-9);
    else
        theta = pi*rand();

```

```

    %Reflection off of verticle face
    Vx(inbox1 & yold >= 60e-9) = V(inbox1 & yold >=
60e-9)*cos(theta);
    Vx(inbox2 & yold <= 40e-9) = V(inbox2 & yold <=
40e-9)*cos(theta);
    Vy(inbox1 & yold >= 60e-9) = V(inbox1 & yold >=
60e-9)*sin(theta);
    Vy(inbox2 & yold <= 40e-9) = V(inbox2 & yold <=
40e-9)*sin(theta);

    %Reflection off of Horizontal Face
    Vy(inbox1 & yold <= 60e-9) = V(inbox1 & yold <=
60e-9)*cos(theta);
    Vy(inbox2 & yold >= 40e-9) = V(inbox2 & yold >=
40e-9)*cos(theta);
    Vx(inbox1 & yold <= 60e-9) = V(inbox1 & yold <=
60e-9)*sin(theta);
    Vx(inbox2 & yold >= 40e-9) = V(inbox2 & yold >=
40e-9)*sin(theta);
end

%Make sure all electrons are in the proper boundary
y(yboundTop) = 100e-9;
y(yboundBottom) = 0;
x(xboundRight) = 200e-9;
x(xboundLeft) = 0;
x(inbox1 & yold >= 60e-9 & x <= 100e-9) = 80e-9;
x(inbox1 & yold >= 60e-9 & x > 100e-9) = 120e-9;
x(inbox2 & yold <= 40e-9 & x <= 100e-9) =80e-9;
x(inbox2 & yold <= 40e-9 & x >= 100e-9) =120e-9;
y(inbox1 & yold <= 60e-9) = 60e-9;
y(inbox2 & yold >= 60e-9) = 40e-9;

xold = x;
yold = y;
x = x + Vx*dt + 0.5*Fx*dt^2/m;
y = y + Vy*dt + 0.5*Fy*dt^2/m;
Vx = Vx + Fx*dt/m;
Vy = Vy + Fy*dt/m;

%Scatter electrons randomly and reassign velocity using Maxwell
Boltzman
%distribution
scatter = rand(1000,1) < (1 - exp(-dt/0.2e-12));
Vx(scatter) = normrnd(0,std,size(Vx(scatter)));
Vy(scatter) = normrnd(0,std,size(Vy(scatter)));

xplot = transpose([xold(1:20) x(1:20)]);
yplot = transpose([yold(1:20) y(1:20)]);
figure(9)
subplot(2,1,1)
Tplot(i) = (1/(2*K))*mean(Vx.^2 + Vy.^2)*m;

```

```
plot(xplot,yplot)
xlim([0 L])
ylim([0 W])
title('Electron Trajectory')
xlabel('x')
ylabel('y')
hold on
plot(1e-9*[80 80 120 120],1e-9*[200 60 60 200])
plot(1e-9*[80 80 120 120],1e-9*[0 40 40 0])

subplot(2,1,2)
plot(Tplot(1:i))
title('Temperature vs Time Step')
xlabel('Number of Time Steps')
ylabel('Temperature (K)')
drawnow
end

figure(10)
hist3([x y], 'CdataMode', 'auto');
view(2);
title('Electron Density');
xlabel('x (m)');
ylabel('y (m)');
title('Electron Density Heat Map');

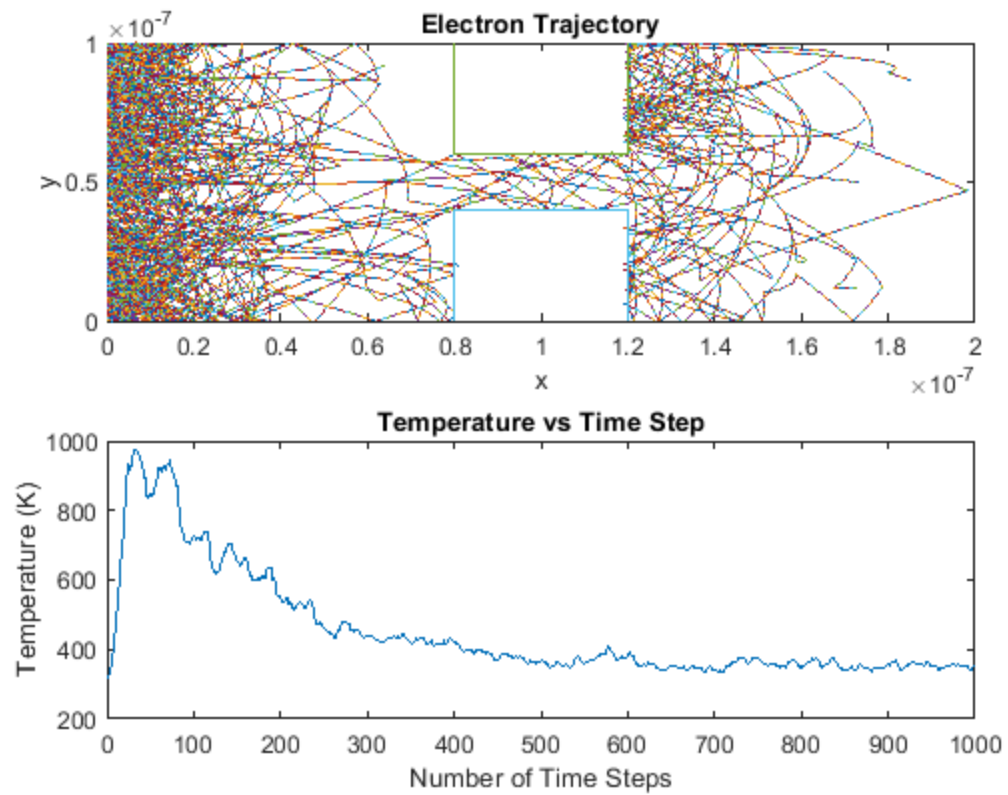
temp_sum_x = zeros(20,10);
temp_sum_y = zeros(20,10);
temp_num = zeros(20,10);

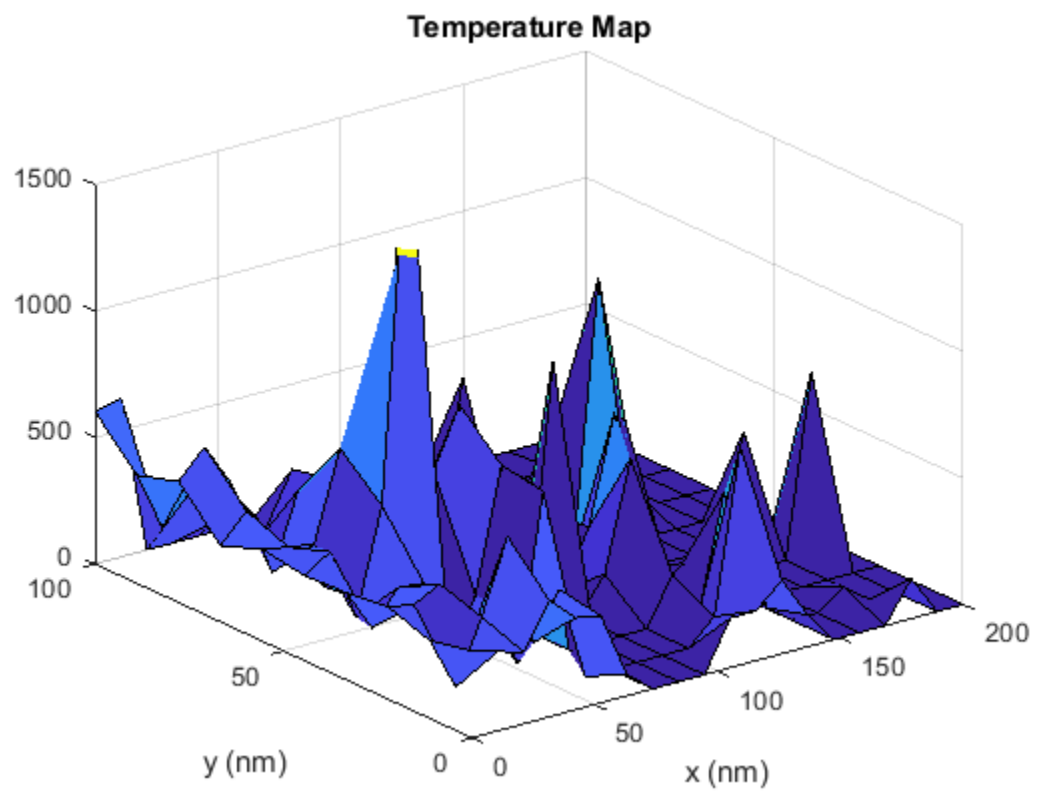
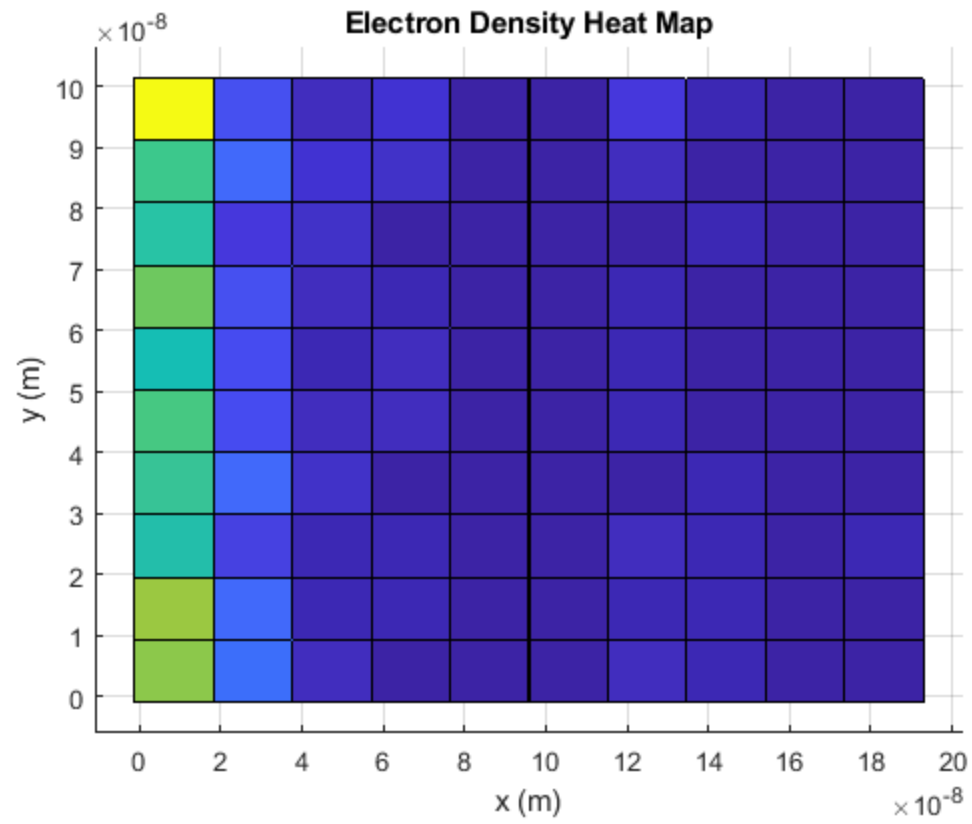
for i=1:1000
    % Find which "bin" it belongs in:
    x1 = floor(x(i)/1e-8);
    y1 = floor(y(i)/1e-8);
    if(x1<=0)
        x1 = 1;
    end
    if(y1<=0)
        y1 = 1;
    end
    if(y1>10)
        y1 = 10;
    end
    if(x1>20)
        x1=20;
    end
    % Add its velocity components to the cumulative count:
    temp_sum_y(x1,y1) = temp_sum_y(x1,y1) + Vy(i).^2;
    temp_sum_x(x1,y1) = temp_sum_x(x1,y1) + Vx(i).^2;
    temp_num(x1,y1) = temp_num(x1,y1) + 1;
end

temp = (temp_sum_x + temp_sum_y).*m./K./2./temp_num;
```

```
temp(isnan(temp)) = 0;
temp = transpose(temp);
```

```
[X Y] = meshgrid(linspace(0,200,20),linspace(0,100,10));
figure(11)
surf(X,Y,temp)
title('Temperature Map');
xlabel('x (nm)');
ylabel('y (nm)');
zlim([0 1500]);
```





Examining the density plots we see that the electrons are heavily grouped towards the left side of the device. This makes sense because this is the positive terminal of the device and the negative electrons will be attracted towards that terminal.

The next step in this simulation is to determine the position of each electron and then re-solve Poisson's equation in order to re-determine the electric field. Then with this new electric field, re-calculate the position of the electrons. This process would be continued throughout the entire simulation. This would increase the accuracy of the simulation but significantly increase the simulation time.

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